## NSN 5961-01-097-2514

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-097-2514 **Inclosure Material:** Plastic **Overall Length:** 0.246 inches **Overall Diameter:** Between 0.395 inches and 0.405 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 400.00 amperes collector current, dc preset and 6.00 amperes collector current, dc absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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